

Josã© Miguel Cunha

List of Publications by Year in descending order

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Version: 2024-02-01

19
papers

385
citations

840776

11
h-index

996975

15
g-index

19
all docs

19
docs citations

19
times ranked

410
citing authors

#	ARTICLE	IF	CITATIONS
1	On the identification of Sb ₂ Se ₃ using Raman scattering. MRS Communications, 2018, 8, 865-870.	1.8	73
2	Passivation of Interfaces in Thin Film Solar Cells: Understanding the Effects of a Nanostructured Rear Point Contact Layer. Advanced Materials Interfaces, 2018, 5, 1701101.	3.7	50
3	Growth of SiO_2 thin films by selenization of RF sputtered binary precursors. Solar Energy Materials and Solar Cells, 2018, 187, 219-226.	6.2	45
4	Optical Lithography Patterning of SiO_2 Layers for Interface Passivation of Thin Film Solar Cells. Solar Rrl, 2018, 2, 1800212.	5.8	44
5	Insulator Materials for Interface Passivation of Cu(In,Ga)Se_2 Thin Films. IEEE Journal of Photovoltaics, 2018, 8, 1313-1319.	2.5	39
6	Rear Optical Reflection and Passivation Using a Nanopatterned Metal/Dielectric Structure in Thin-Film Solar Cells. IEEE Journal of Photovoltaics, 2019, 9, 1421-1427.	2.5	21
7	A morphological and electronic study of ultrathin rear passivated Cu(In,Ga)Se_2 solar cells. Thin Solid Films, 2019, 671, 77-84.	1.8	21
8	Phase selective growth of $\text{Cu}_{12}\text{Sb}_4\text{S}_{13}$ and Cu_3SbS_4 thin films by chalcogenization of simultaneous sputtered metal precursors. Journal of Alloys and Compounds, 2019, 797, 1359-1366.	5.5	16
9	Understanding the AC Equivalent Circuit Response of Ultrathin Cu(In,Ga)Se_2 Solar Cells. IEEE Journal of Photovoltaics, 2019, 9, 1442-1448.	2.5	15
10	High-Performance and Industrially Viable Nanostructured SiO_2 Layers for Interface Passivation in Thin Film Solar Cells. Solar Rrl, 2021, 5, 2000534.	5.8	15
11	Muon implantation experiments in films: Obtaining depth-resolved information. Review of Scientific Instruments, 2020, 91, 023906.	1.3	13
12	On the Importance of Joint Mitigation Strategies for Front, Bulk, and Rear Recombination in Ultrathin Cu(In,Ga)Se_2 Solar Cells. ACS Applied Materials & Interfaces, 2021, 13, 27713-27725.	8.0	11
13	Encapsulation of Nanostructures in a Dielectric Matrix Providing Optical Enhancement in Ultrathin Solar Cells. Solar Rrl, 2020, 4, 2000310.	5.8	10
14	Decoupling of Optical and Electrical Properties of Rear Contact CIGS Solar Cells. IEEE Journal of Photovoltaics, 2019, 9, 1857-1862.	2.5	7
15	Photovoltaics: Passivation of Interfaces in Thin Film Solar Cells: Understanding the Effects of a Nanostructured Rear Point Contact Layer (Adv. Mater. Interfaces 2/2018). Advanced Materials Interfaces, 2018, 5, 1870007.	3.7	2
16	Characterization of the Interfacial Defect Layer in Chalcopyrite Solar Cells by Depth-Resolved Muon Spin Spectroscopy. Advanced Materials Interfaces, 0, , 2200374.	3.7	2
17	Perovskite Metal-Oxide Semiconductor Structures for Interface Characterization. Advanced Materials Interfaces, 2021, 8, 2101004.	3.7	1
18	Equivalent Circuit For AC Response of Cu(In,Ga)Se_2 Thin Film Solar Cells. , 2019, , .		0

#	ARTICLE	IF	CITATIONS
19	High-Performance and Industrially Viable Nanostructured SiO _x Layers for Interface Passivation in Thin Film Solar Cells. Solar Rrl, 2021, 5, 2170036.	5.8	0